# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

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## TIP131, TIP132 (NPN), TIP137 (PNP)

## **Darlington Complementary Silicon Power Transistors**

Designed for general-purpose amplifier and low-speed switching applications.

#### Features

- High DC Current Gain  $h_{FE} = 2500 (Typ) @ I_C$ 
  - = 4.0 Adc
- Collector-Emitter Sustaining Voltage @ 30 mAdc
  V<sub>CEO(sus)</sub> = 80 Vdc (Min) TIP131
  = 100 Vdc (Min) TIP132, TIP137
- Low Collector–Emitter Saturation Voltage
  - $V_{CE(sat)} = 2.0 \text{ Vdc} (Max) @ I_C = 4.0 \text{ Adc}$

 $= 3.0 \text{ Vdc} (\text{Max}) @ I_{\text{C}} = 6.0 \text{ Adc}$ 

- Monolithic Construction with Built-In Base-Emitter Shunt Resistors
- Pb-Free Packages are Available\*

#### MAXIMUM RATINGS

Rating	Symbol	TIP131	TIP132 TIP137	Unit
Collector-Emitter Voltage	V <sub>CEO</sub>	80	100	Vdc
Collector-Base Voltage	V <sub>CB</sub>	80	100	Vdc
Emitter-Base Voltage	V <sub>EB</sub>	5.	0	Vdc
Collector Current – Continuous Peak	Ι <sub>C</sub>	8. 1	0 2	Adc
Base Current	I <sub>B</sub>	30	00	mAdc
Total Power Dissipation @ $T_C = 25^{\circ}C$	PD	7	0	W
Total Power Dissipation @ $T_A = 25^{\circ}C$	PD	2.	0	W
Operating and Storage Junction, Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to	+150	°C

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	1.78	°C/W
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	63.5	°C/W

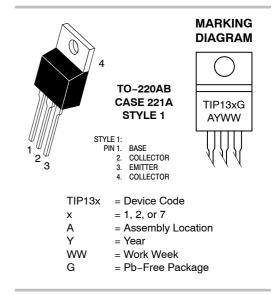
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



#### **ON Semiconductor®**

http://onsemi.com

#### DARLINGTON 8 AMPERE COMPLEMENTARY SILICON POWER TRANSISTORS 80–100 VOLTS, 70 WATTS



#### ORDERING INFORMATION

Device	Package	Shipping
TIP131	TO-220	50 Units/Rail
TIP131G	TO-220 (Pb-Free)	50 Units/Rail
TIP132	TO-220	50 Units/Rail
TIP132G	TO–220 (Pb–Free)	50 Units/Rail
TIP137	TO-220	50 Units/Rail
TIP137G	TO-220 (Pb-Free)	50 Units/Rail

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### TIP131, TIP132 (NPN), TIP137 (PNP)

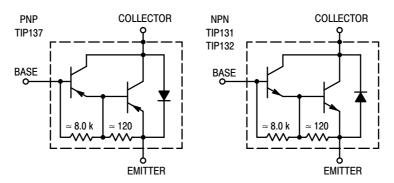


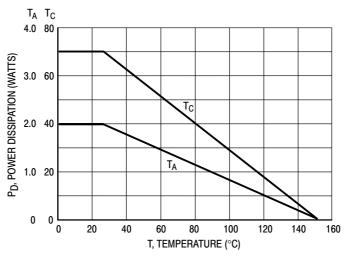
Figure 1. Darlington Circuit Schematic

## ELECTRICAL CHARACTERISTICS (T<sub>C</sub> = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit		
OFF CHARACTERISTICS							
Collector-Emitter Sustaining Voltage (Note 1) $(I_{C} = 30 \text{ mAdc}, I_{B} = 0)$	TIP131 TIP132, TIP137	V <sub>CEO(sus)</sub>	80 100		Vdc		
Collector Cutoff Current ( $V_{CE} = 40 \text{ Vdc}, I_B = 0$ ) ( $V_{CE} = 50 \text{ Vdc}, I_B = 0$ )	TIP131 TIP132, TIP137	I <sub>CEO</sub>		0.5 0.5	mAdc		
Collector Cutoff Current ( $V_{CB} = 80$ Vdc, $I_E = 0$ ) ( $V_{CB} = 100$ Vdc, $I_E = 0$ )	TIP131 TIP132, TIP137	I <sub>CBO</sub>		0.2 0.2	mAdc		
Emitter Cutoff Current ( $V_{BE}$ = 5.0 Vdc, I <sub>C</sub> = 0)		I <sub>EBO</sub>	-	5.0	mAdc		
ON CHARACTERISTICS (Note 1)			•		•		
DC Current Gain ( $I_C = 1.0$ Adc, $V_{CE} = 4.0$ Vdc) ( $I_C = 4.0$ Adc, $V_{CE} = 4.0$ Vdc)		h <sub>FE</sub>	500 1000	_ 15000	-		
Collector-Emitter Saturation Voltage ( $I_C = 4.0 \text{ Adc}, I_B = 16 \text{ mAdc}$ ) ( $I_C = 6.0 \text{ Adc}, I_B = 30 \text{ mAdc}$ )		V <sub>CE(sat)</sub>		2.0 3.0	Vdc		
Base-Emitter On Voltage (I <sub>C</sub> = 4.0 Adc, V <sub>CE</sub> = 4.0 Vdc)		V <sub>BE(on)</sub>	-	2.5	Vdc		

1. Pulse Test: Pulse Width  $\leq$  300 µs, Duty Cycle  $\leq$  2%.

#### TIP131, TIP132 (NPN), TIP137 (PNP)





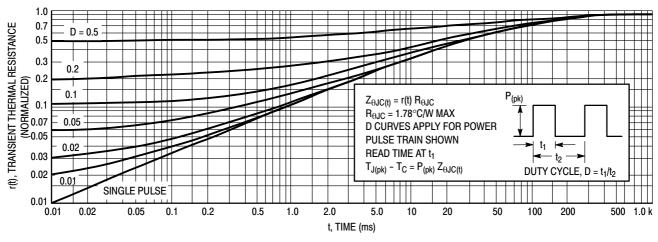
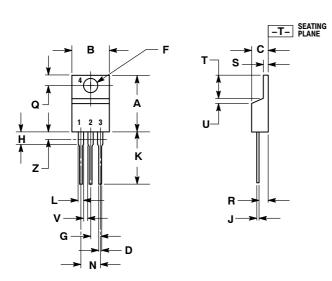


Figure 3. Thermal Response

#### TIP131, TIP132 (NPN), TIP137 (PNP)

#### PACKAGE DIMENSIONS

TO-220 CASE 221A-09 ISSUE AG



	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.036	0.64	0.91
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
Н	0.110	0.161	2.80	4.10
L	0.014	0.025	0.36	0.64
Κ	0.500	0.562	12.70	14.27
Г	0.045	0.060	1.15	1.52
Ν	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
s	0.045	0.055	1.15	1.39
Т	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
۷	0.045		1.15	
Ζ		0.080		2.04

NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI

DIMENSION Z DEFINES A ZONE WHERE ALL

2. CONTROLLING DIMENSION: INCH.

Y14.5M, 1982.

3.

STYLE 1: PIN 1. BASE

2. COLLECTOR 3. EMITTER

4. COLLECTOR

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